

Green Products

MBR5100S SCHOTTKY RECTIFIER

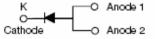
Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

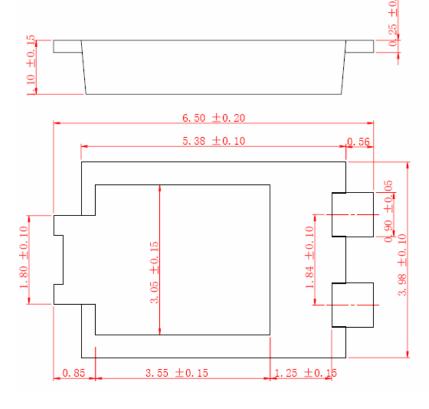
Features:

- Designed as Bypass Diodes for Solar Panels
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





Mechanical Dimensions: In mm





TO-277B

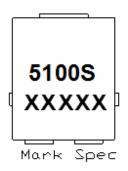
[•] Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

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Marking Diagram:



Where XXXXX is YYWWL

5 = Forward Current (5A) 100 = Reverse Voltage (100V)

S = Device Type

YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBR5100S	TO-277B (Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	100	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C = 105°C, rectangular wave form	5	Α
Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	120	А

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Electrical Characteristics:

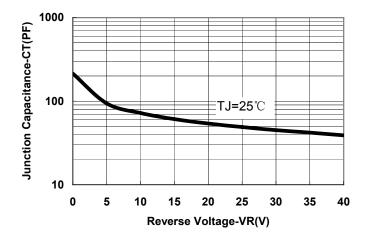
Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop	V_{F1}	@ 5A, Pulse, T _J = 25 °C	0.85	V
	V_{F2}	@ 5A, Pulse, T _J = 125 °C	0.70	V
Reverse Current	I _{R1}	$@V_R = rated V_R$ $T_J = 25 °C$	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 125^{\circ}C$	10	mA

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	DC operation	25	°C/W
Approximate Weight	wt	-	0.08	g
Case Style		TO-277B		

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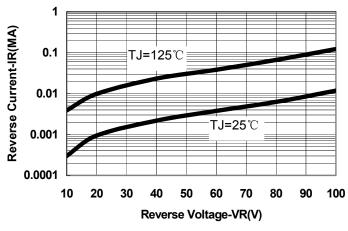


Fig.1-Typical Junction Capacitance Vs.Reverse Voltage

Fig.2-Typical Values Of Reverse Current Vs.Reverse Voltage

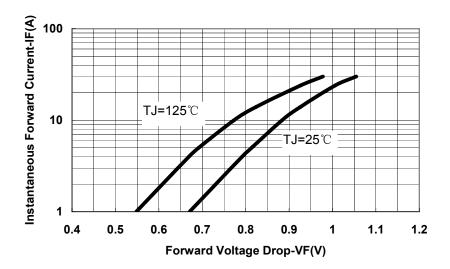


Fig.3-Typical Forward Voltage Drop Characteristics

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